# InGaAs Single-Photon Avalanche Diodes (SPADs)



#### **Description:**

InGaAs avalanche photodiode (APD) is a special device for short wave near-infrared single photon detection. It can meet the technical requirements for high-efficiency and low-noise single photon detection in the fields of quantum communication and weak light detection, and realize the detection of  $0.9 \sim 1.7 \mu$  m wavelength single photon detection.

#### Features:

- Spectral response range: 0.9 ~ 1.7 μ m
- High detection efficiency and low dark counting rate
- 3 pin TO46

#### **Optional:**

- Weak light detection
- Quantum secure communication
- Biomedicine



## Linear mode parameters:

Product model			IGA-APD-GM104-R			
parameters	Symbol	unit	Test conditions	min	typical	max
Reverse breakdown voltage	VBR	V	22°C±3°C ID =10µA	60	80	90
Reponsivity	Re	A/W	22°C±3°C, λ=1550nm, M=1	0.8	0.85	
Dark current	ID	nA	22°C±3°C, M=10		0.1	0.3
Capacitance	С	PF	22°C±3°C, M=10, f=1MHz			0.25
Breakdown voltage temperature coefficient	η	V/K	-40°C~80°C ID=10µA			0.15

## Geiger mode parameters:

parameters	unit	Test conditions		typical	max
Single Photon Detection Efficiency (PDE)	%	-45°C, λ =1550nm,0.1ph/pulse			
		Poisson distribution single photon source 20			
Dack count rate (DCR)	kHz	-45°C, 1ns gate width, 2MHz Gated repetition frequency,			20*
After pulse probability (APP)		1MHz Optical repetition frequency, PDE=20%			
Time jitter (Tj)	ps	-45°C, 1ns gate width, 2MHz Gated repetition frequency,			1×10 <sup>-3</sup>
		1MHz Optical repetition frequency, PDE=20%			100
		-45°C, 1ns gate width, 2MHz Gated repetition frequency, PDE=20%			

### **Dimensions and Pin definitions:**

#### TO46 (pigtail package)

Unit: mm





PIN #	Definition	
1	P(anode)	
2	Ground	
3	N(cathode)	

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